



Receipt

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PATENT
5500-05001/TT1915D

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:
Gardner et al.

Group Art Unit: 2814

Serial No. 09/217,213

Atty. Dkt.: 5500-05001

Filed: December 21, 1998

For: SEMICONDUCTOR FABRICATION
EMPLOYING IMPLANTATION
OF EXCESS ATOMS AT THE
EDGES OF A TRENCH ISOLATION
STRUCTURE

I hereby certify that this correspondence is being deposited
with the U.S. Postal Service as First Class Mail in an envelope
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Washington, D.C. 20231, on the date indicated below:

February 5, 1999
Date

Signature of Kevin L. Daffer
Kevin L. Daffer

REQUEST FOR CORRECTED OFFICIAL FILING RECEIPT

Application Processing Division
Customer Correction Branch
United States Department of Commerce
Patent & Trademark Office
Washington, D.C. 20231

Sir:

The official Filing Receipt received by our office on January 19, 1999, has a misspelled word in the title. The word "Trence" should be spelled **Trench**. I have provided a copy of the Filing Receipt with the change noted thereon. Applicants respectively request that this change be made and a corrected Filing Receipt be reissued in the above-identified application.

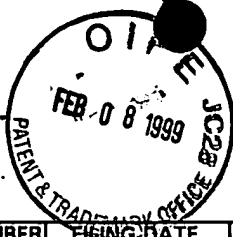
Respectfully submitted,

Signature of Kevin L. Daffer
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FILING RECEIPT



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APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTORNEY DOCKET NO.	DRWGS	TOT CL	IND CL
09/217,213	12/21/98	2814	\$760.00	5500-05001	5	9	2

KEVIN L DAFFER
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Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Application Processing Division's Customer Correction Branch within 10 days of receipt. Please provide a copy of the Filing Receipt with the changes noted thereon.

Applicant(s)

MARK I. GARDNER, CEDAR CREEK, TX; H. JIM FULFORD,
AUSTIN, TX; DERICK J. WRISTER, AUSTIN, TX.

CONTINUING DATA AS CLAIMED BY APPLICANT-

THIS APPLN IS A DIV OF 08/923,181 09/04/97

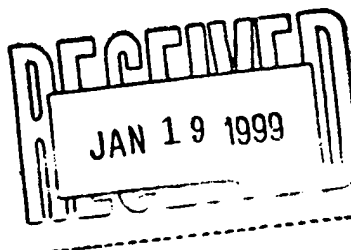
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TITLE

SEMICONDUCTOR FABRICATION EMPLOYING IMPLANTATION OF EXCESS ATOMS AT
THE EDGES OF A TRENCH ISOLATION STRUCTURE

TRENCH

PRELIMINARY CLASS: 438



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DATA ENTRY BY: ZIMMERMAN, SHUANA

TEAM: 01 DATE: 01/14/99